

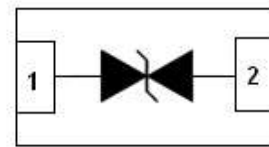
FEATURES:

- ✧ Protects one bi-directional I/O line
- ✧ Low clamping voltage
- ✧ Low operating voltage: 5V
- ✧ ROHS compliant

**MAIN APPLICATIONS**

- ✧ Cell Phone Handsets and Accessories
- ✧ Personal Digital Assistants (PDA's)
- ✧ Notebooks, Desktops, and Servers
- ✧ Portable Instrumentation
- ✧ Pagers
- ✧ Microprocessor based equipment

SOD-882



PIN Configuration

PROTECTION SOLUTION TO MEET

- ✧ IEC61000-4-2 (ESD) $\pm 20\text{kV}$ (air), $\pm 20\text{kV}$ (contact)
- ✧ IEC61000-4-5 (Lighting) 4.0A (8/20us)

MECHANICAL CHARACTERISTICS

- ✧ Package SOD-882
- ✧ Molding Compound Flammability Rating : UL 94V-O
- ✧ Quantity Per Reel : 10,000pcs
- ✧ Lead Finish : Lead Free
- ✧ Marking code: 50

ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, RH=45%-75%, unless otherwise noted)

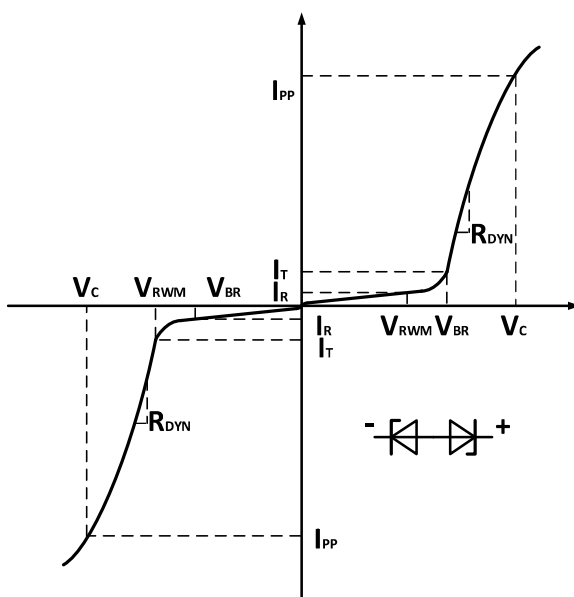
Parameter	Symbol	Value	Unit
Storage temperature range	T_{stg}	-55 to +150	$^\circ\text{C}$
Operating junction temperature range	T_j	-55 to +125	$^\circ\text{C}$
Lead Soldering Temperature	T_L	260 (10 sec.)	$^\circ\text{C}$
Peak pulse power dissipation on 8/20 μs waveform	P_{PP}	88	W
ESD per IEC 61000-4-2 (Air)	V_{ESD}	+/- 20	kV
ESD per IEC 61000-4-2 (Contact)		+/- 20	

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Reverse Working Voltage	V_R				5	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	6.0			V
Reverse Leakage Current	I_R	$V_R = 5\text{V}$			1.0	μA
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu\text{s}$			4.0	A
Clamping Voltage	V_C	$I_{PP} = 1.0\text{A}$, $t_p = 8/20\mu\text{s}$			13	V
		$I_{PP} = 4.0\text{A}$, $t_p = 8/20\mu\text{s}$			22	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$		0.22	0.35	pF

RATINGS AND V-I CHARACTERISTICS CURVES

Symbol	Parameter
V_{RWM}	Reverse Standoff Voltage
I_R	Max Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Max Peak Pulse Current
R_{DYN}	Dynamic Resistance
C_J	Junction Capacitance
P_{PP}	Peak Pulse Power



RATINGS AND V-I CHARACTERISTICS CURVES ($T_A=25^\circ\text{C}$, unless otherwise noted)

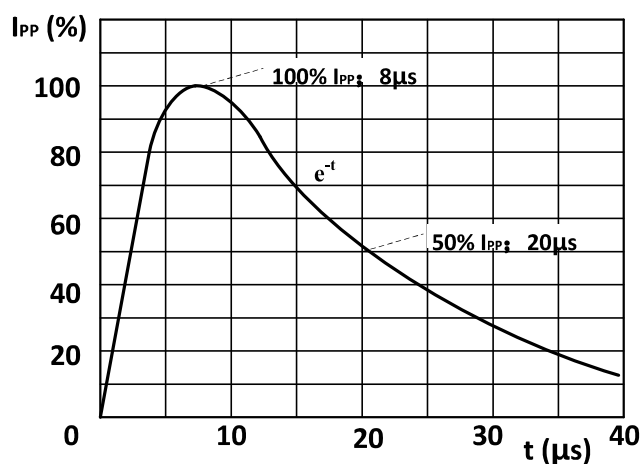


Fig. 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

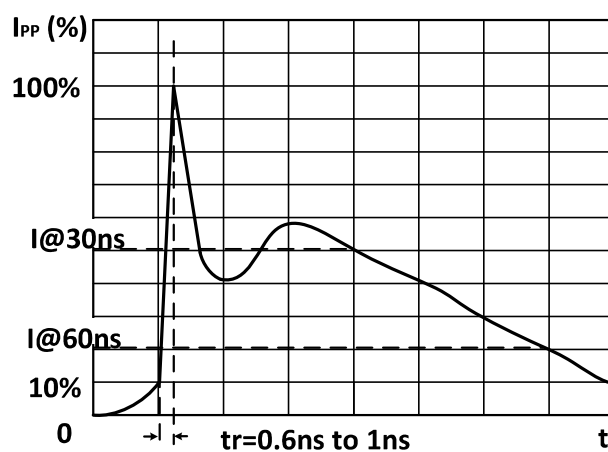


Fig. 2. ESD pulse waveform according to IEC 61000-4-2

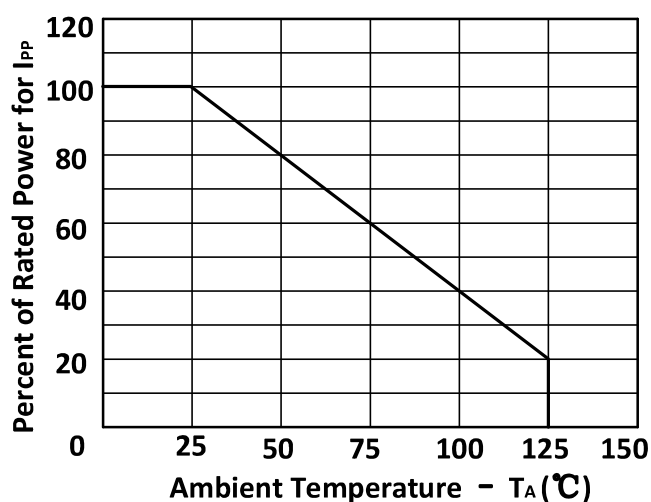


Fig. 3. Power Derating Curve

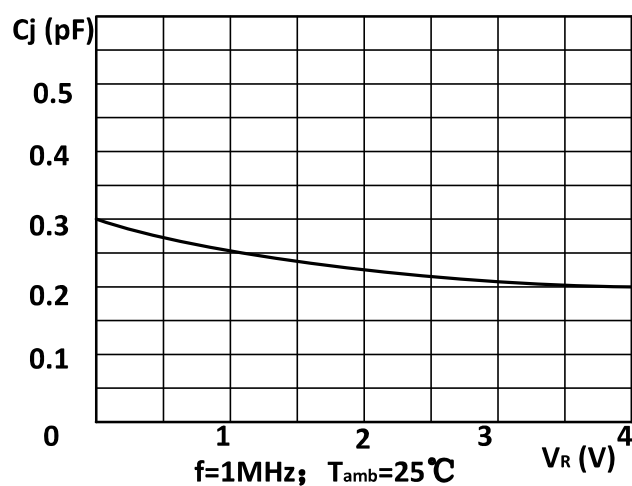
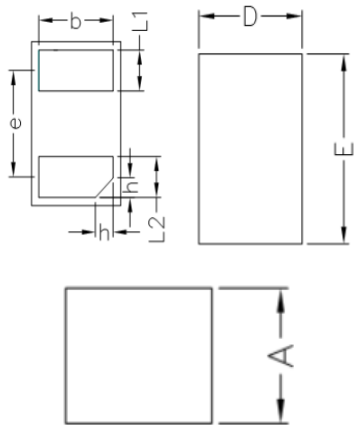


Fig. 4. Junction Capacitance vs V_R

PACKAGE MECHANICAL DATA

SOD-882 	Symbol	Millimeters		
		min	nom	max
	D	0.55	0.60	0.65
	E	0.95	1.00	1.05
	L1	0.20	0.25	0.30
	L2	0.20	0.25	0.30
	b	0.45	0.50	0.55
	e	0.65BSC		
	A	0.45	0.50	0.55
	h	0.07	0.12	0.17